

10/512131

DT01 Rec'd PCT/PTO 21 OCT 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Okuyama et al.  
Intnl. Appl. No.: PCT/JP04/001952  
Intnl. Filing Date: February 19, 2004  
Title: SEMICONDUCTOR LIGHT EMITTING ELEMENT,  
MANUFACTURING METHOD THEREOF, INTEGRATED  
SEMICONDUCTOR LIGHT EMITTING DEVICE,  
MANUFACTURING METHOD THEREOF, IMAGE DISPLAY  
DEVICE, MANUFACTURING METHOD THEREOF,  
ILLUMINATING DEVICE AND MANUFACTURING METHOD  
THEREOF  
Docket No.: 112857-534

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**INFORMATION DISCLOSURE STATEMENT**

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 37 C.F.R. 1.97, and 37 C.F.R. 1.98, Applicants request that a citation and examination of the references cited below, and on the attached PTO-1449 form, copies of which are enclosed, be made during the course of examination of the above-identified application for United States patent.

**FOREIGN PATENT DOCUMENTS**

<u>Document No.</u>	<u>Date</u>	<u>Country</u>
06-045648	02-18-1994	Japan
09-129974	05-16-1997	Japan
11-026883	01-29-1999	Japan
2002-100805	04-05-2002	Japan
2002-261327	09-13-2002	Japan

**OTHER DOCUMENTS**

Tachibana, K. et al., "Selective growth of InGaN quantum dot structures and their microphotoluminescence at room temperature," Applied Physics Letters, 29 May, 2000, Vol. 76, No. 22, pp. 3212-3214.

10/512131

DT01 Rec'd PCT/PTC 21 OCT 2004

Applicants look forward to early and favorable consideration of this matter.

Respectfully submitted,

BELL, BOYD & LLOYD LLC

BY 

Thomas C. Basso

Reg. No. 46,541

P.O. Box 1135

Chicago, Illinois 60690-1135

Phone: (312) 807-4310

Dated: October 21, 2004

<b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION</b> (Use several sheets if necessary) PTO Form 1449		Atty Docket No. 112857-534	Application No. 10/512131
		Applicant Okuyama et al.	
		Filing Date October 21, 2004	Group Unknown

<b>U.S. PATENT DOCUMENTS</b>							
Examiner's Initials		Document Number	Publication Date	Inventor	Class	Subclass	Filing Date If Appropriate

<b>FOREIGN PATENT DOCUMENTS</b>							
Examiner's Initials		Document Number	Publication Date	Country	Class	Subclass	Translation
							Yes No
		06-045648	02-18-1994	Japan			
		09-129974	05-16-1997	Japan			
		11-026883	01-29-1999	Japan			
		2002-100805	04-05-2002	Japan			
		2002-261327	09-13-2002	Japan			

Examiner's Initials	<b>OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)</b>
	Tachibana, K. et al., "Selective growth of InGaN quantum dot structures and their microphotoluminescence at room temperature," Applied Physics Letters, 29 May, 2000, Vol. 76, No. 22, pp. 3212-3214.

Examiner:	Date Considered:
*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	